# imall

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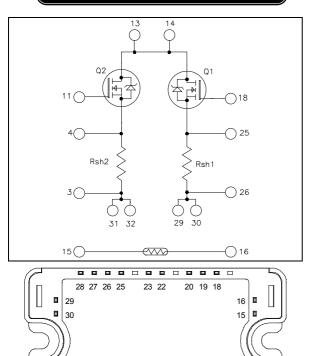
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Linear MOSFET Power Module



#### 

#### Pins 13/14 ; 29/30 ; 31/32 must be shorted together

#### Absolute maximum ratings (per leg)

**1** 31

Symbol	Parameter		Max ratings	Unit	
V <sub>DSS</sub>	Drain - Source Breakdown Voltage		500	V	
т	Continuous Drain Current	$T_c = 25^{\circ}C$	52*		
I <sub>D</sub>	Continuous Drain Current	$T_c = 80^{\circ}C$	39*	А	
I <sub>DM</sub>	Continuous Drain Current $T_c = 80^{\circ}C$ Pulsed Drain currentGate - Source VoltageDrain - Source ON Resistance		200		
V <sub>GS</sub>			±30	V	
R <sub>DSon</sub>	Drain - Source ON Resistance		108	mΩ	
P <sub>D</sub>	Maximum Power Dissipation $T_c = 25^{\circ}C$		568	W	
I <sub>AR</sub>	Avalanche current (repetitive and non repetitive)		52	Α	
E <sub>AR</sub>	Repetitive Avalanche Energy		50	mJ	
E <sub>AS</sub>	Single Pulse Avalanche Energy		3000	1115	

14 🗖

\* Output current must be limited to 31A @  $T_c=25^{\circ}C$  and 22A @  $T_c=80^{\circ}C$  to not exceed the shunt specification. • In saturation mode

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

### APTML502UM90R020T3AG

$$V_{DSS} = 500V$$
  

$$R_{DSon} = 90m\Omega \text{ typ } @ \text{ Tj} = 25^{\circ}\text{C}$$
  

$$I_{D} = 52\text{A}^{*} @ \text{ Tc} = 25^{\circ}\text{C}$$

#### Application

• Electronic load dedicated to power supplies and battery discharge testing

#### Features

- Linear MOSFET
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration
- AlN substrate for improved thermal performance

#### Benefits

- Direct mounting to heatsink (isolated package)
- easy series and parallels combinations for power and voltage improvements
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant



**Microsemi** Aptml502um90r020t3AG

#### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

#### Electrical Characteristics (per leg)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 500V$ ; $V_{GS} = 0V$	$T_j = 25^{\circ}C$			25		
		$V_{DS} = 400V$ ; $V_{GS} = 0V$	$T_j = 125^{\circ}C$			250	μA	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 26A$			90	108	mΩ	
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 2.5 \text{mA}$		2		4	V	
I <sub>GSS</sub>	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}$				±100	nA	

#### Dynamic Characteristics (per leg)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	Input Capacitance	$V_{GS} = 0V$		7600		
C <sub>oss</sub>	Output Capacitance	$V_{\rm DS} = 25V$		1280		pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1 MHz		620		

#### Shunt Electrical Characteristics (per leg)

Symbol	Characteristic		Min	Тур	Max	Unit
R <sub>sh</sub>	Resistance value			20		mΩ
T <sub>sh</sub>	Tolerance			2		%
P <sub>sh</sub>		T <sub>C</sub> =25°C			20	W
r <sub>sh</sub>		T <sub>C</sub> =80°C			10	vv
I <sub>sh</sub>	Current capacity	T <sub>C</sub> =25°C		31	٨	
		$T_{C}=80^{\circ}C$			22	A

#### **Temperature sensor PTC**

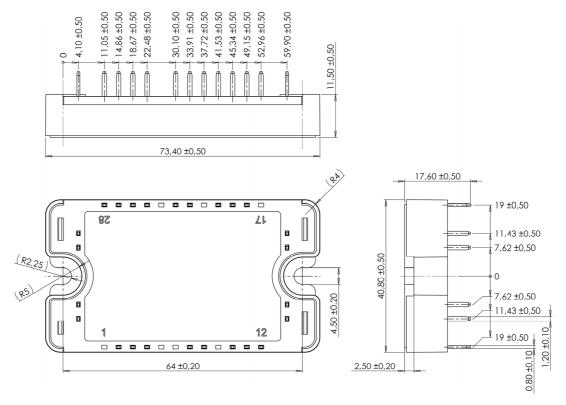
Symbol	Characteristic		Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		1980		2020	Ω
$R_{100}/R_{25}$	Resistance ratio	Tamb=100°C & 25°C	1.676	1.696	1.716	
$R_{-55}/R_{25}$	Resistance ratio	Tamb=-55°C & 25°C	0.48	0.49	0.50	
В	Temperature coefficient			7900		ppm/K

#### Thermal and package characteristics

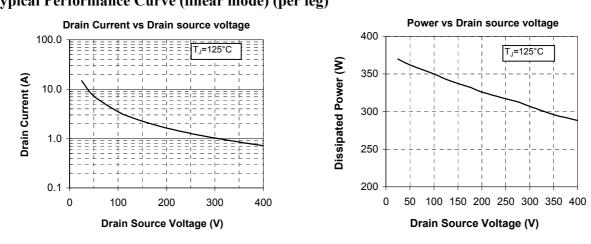
Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance	MOSFET (	per leg)			0.22	°C/W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range		-40		150		
T <sub>STG</sub>	Storage Temperature Range			-40		125	°C
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					110	g



#### SP3 Package outline (dimensions in mm)



See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com



### Typical Performance Curve (linear mode) (per leg)

www.microsemi.com



### APTML502UM90R020T3AG

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